

14701 Firestone Blvd. * La Mirada, Ca 90638 Phone: (562) 404-4474 * Fax: (562) 404-1773 ssdi@ssdi-power.com * www.ssdi-power.com

Designer's Data Sheet

Part Number / Ordering Information 1/

SED10____45___

L Screening^{2/} = None TX = TX Level TXV = TXV Level S = S Level

- L Configuration
 - HB = without lead HE = with lead HF = with lead, reverse polarity

SED10HB45, SED10HE45 and SED10HF45

10 AMP 45 VOLTS SCHOTTKY RECTIFIER

FEATURES:

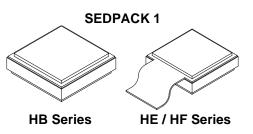
- Low Reverse Leakage
- Low Forward Voltage Drop
- Hermetically Sealed Power Surface
 Mount Package
- Guard Ring for Overvoltage Protection
- Eutectic Die Attach
- 175°C Operating Temperature
- TX, TXV, and Space Level Screening Available^{2/}

MAXIMUM RATINGS		Symbol	Value	Unit
Peak Repetitive Reverse Voltage and DC Blocking Voltage		V _{RRM} V _{RWM} V _R	45	V
Average Rectified Forward Current (Resistive Load, 60 Hz, Sine Wave, $T_A = 100^{\circ}C$)		lo	10	Α
Peak Surge Current (8.3 ms Pulse, Half Sine Wave, 1 pulse, $T_A = 25^{\circ}C$)		I _{FSM}	250	Α
Operating and Storage Temperature		T _{OP} & T _{stg}	-55 to +175	°C
Maximum Thermal Resistance Junction to Case	SED10HB45 SED10HE45 SED10HF45	R _{θJC}	1.25 1.25 3.00	°C/W

Notes: *Pulsed per MIL-STD-750.

 For ordering information, price, operating curves, and availability – contact factory.

2/ Screening based on MIL-PRF-19500. Screening flows available on request.

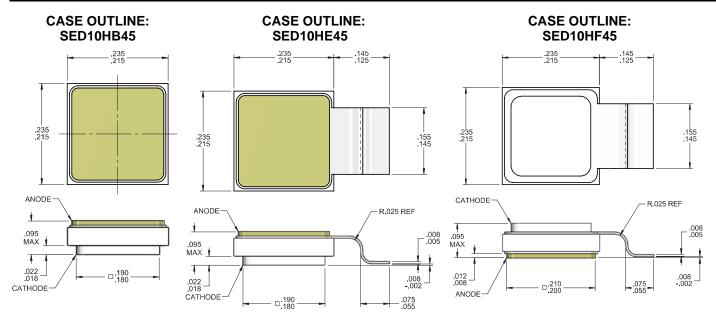




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ELECTRICAL CHARACTERISTICS		Symbol	Maximum	Typical	Unit
Instantaneous Forward Voltage Drop (IF = 5 ADC, pulsed)	T _A = -55°C T _A = 25°C T _A = 125°C	V _{F1} V _{F2} V _{F3}	- 0.52 -	0.58 0.48 0.36	V _{DC}
Instantaneous Forward Voltage Drop (IF = 10 ADC, pulsed)	T _A = -55°C T _A = 25°C T _A = 125°C	V _{F4} V _{F5} V _{F6}	- 0.56 0.49	0.62 0.54 0.44	V _{DC}
Instantaneous Forward Voltage Drop (I _F = 20 A _{DC} , pulsed)	T _A = -55°C T _A = 25°C T _A = 125°C	V _{F7} V _{F8} V _{F9}	- 0.69 -	0.69 0.64 0.57	V _{DC}
Reverse Leakage Current (Rated V _R , pulsed)	T _A = 25°C T _A = 100°C T _A = 125°C	I _{R1} I _{R2} I _{R3}	0.25 - 25	0.02 3 18	mA
Junction Capacitance (T _A = 25°C, f = 1 MHz)	V _R = 5 V V _R = 10 V	C _{J1} C _{J2}	900 -	780 580	pF



Notes: *Pulsed per MIL-STD-750.

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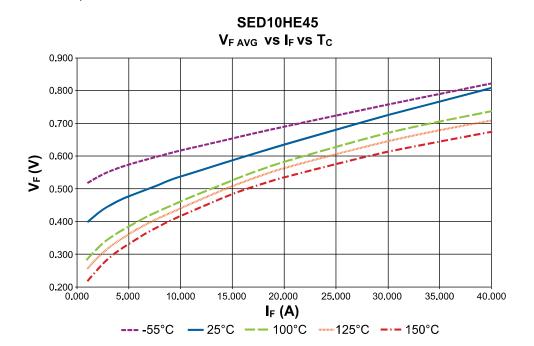
NOTE: All specifications are subject to change without notification. SCD's for these devices should be reviewed by SSDI prior to release.	DATA SHEET #: RS0002K	DOCX
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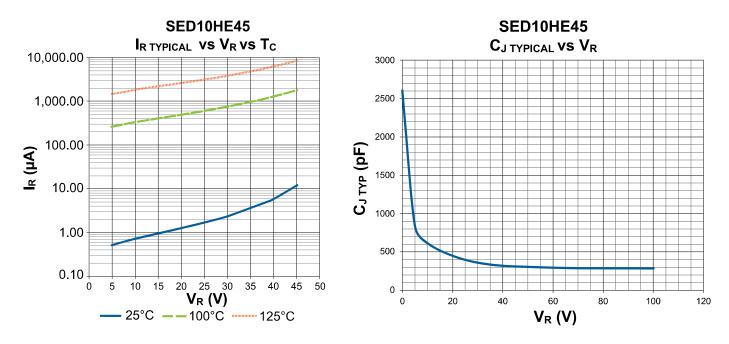


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